Charge-density waves in the mixed-valence two-dimensional metal $K_3Cu_8S_6$

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In order to study the physical properties of $K_3Cu_8S_6$, we have carefully defined the synthetic conditions for KCu₄S₃, K₃Cu₈S₆, and KCu₃S₂. K₃Cu₈S₆ is apparently a kinetic phase and must be trapped with a minimum amount of either KCu₄S₃ or KCu₃S₂. Magnetic susceptibility and electrical resistivity data display behavior typical of charge-density-wave systems. In view of the lowdimensional metallic nature of K₃Cu₈S₆ and preliminary x-ray data, a second-order reversible transition at $T_1 = 152 \pm 1$ K has been identified as the onset of an incommensurate lattice. In the region of 50-60 K, a first-order transition with considerable hysteresis seems to be a structural transition to a commensurate superlattice state.

I. INTRODUCTION

Rudorff *et al.*¹ first reported the existence of the composition $K_3Cu_8S_6$ as part of an investigation concerning the products of high-temperature fusion reactions involving alkali-metal carbonates, copper, and sulfur. Their results indicated that the new phases $Na_2Cu_3S_3$, KCu_4S_3 , $RbCu_4S_3$, and $K_3Cu_8S_6$ all have metallic conductivity at room temperature ($\approx 50-100 \ \Omega^{-1} \text{ cm}^{-1}$) in addition to a blue-black metallic lustre. Stimulated by the apparent "mixed valency" of the Cu (e.g., Cu⁺ and Cu²⁺) and the electrical conductivity of these compounds, a number of workers have taken a closer look at the structural and physical properties of some of these materials.

The composition "Na₂Cu₃S₃" was reported by Rudorff¹ as the sole product of the fusion reaction between copper, sulfur, and sodium carbonate. More recent results by both Burschka² and Brown³ have shown that this Na₂Cu₃S₃ phase is actually Na₃Cu₄S₄, and can be described as a one-dimensional metal. The structure consists of one-dimensional columns of $[Cu_4S_4]^{3-}$ chains separated by sodium ions, and the physical properties are in agreement with metallic behavior.

Brown⁴ has also reported single-crystal x-ray diffraction results and physical properties for the KCu₄S₃ phase reported by Rudorff.¹ Their results indicate that KCu₄S₃ adopts a double-layer structure (S-Cu-S) and exhibits metallic behavior. Therefore, KCu₄S₃ is a twodimensional metal as opposed to the one-dimensional example provided by Na₃Cu₄S₄. Burschka⁵ has reported the structure for CsCu₄S₃ and found it to be isotypic with KCu₄S₃ and RbCu₄S₃.

The first attempts by Burschka to synthesize $K_3Cu_8S_6$ were unsuccessful and led to the discovery of the as yet unknown compound KCu_3S_2 .⁶ Interestingly, Burschka⁵ has also found that $CsCu_3S_2$ exists, but that it adopts a new structure type which is totally unlike that of KCu_3S_2 . In subsequent work, Burschka⁷ succeeded in synthesizing $K_3Cu_8S_6$ and reported the results of a single-crystal x-ray diffraction study. The synthetic conditions Burschka reported were, however, in conflict with those reported by Rudorff.¹ In a closely related study, Schils *et al.*⁸ reported the synthesis and structure of the isotypic compounds Rb₃Cu₈Se₆ and Cs₃Cu₈Se₆.

Stimulated by the variety of compounds obtained from this series of alkali-metal carbonate fusion reactions as well as the intriguing combination of unusual structure and metallic conductivity, we have reinvestigated the synthesis of $K_3Cu_8S_6$ in order to investigate its physical properties. Both magnetic susceptibility and electrical resistivity measurements were made, and both show remarkably unusual behavior, behavior which we feel is most likely attributable to the presence of a charge-density wave (CDW).

II. SYNTHESIS

There are three K-Cu-S phases which can be obtained from high-temperature fusion reactions involving K_2CO_3 , powdered copper, and elemental sulfur. Namely, these are KCu_4S_3 (or $K_2Cu_8S_6$), $K_3Cu_8S_6$, and KCu_3S_2 (or $K_3Cu_9S_6$). It is interesting to note at this point the stoichiometric relationship,

$$K_2 Cu_8 S_6 \xrightarrow{K} K_3 Cu_8 S_6 \xrightarrow{Cu} K_3 Cu_9 S_6 , \qquad (1)$$

since there are also synthetic and structural trends which systematically vary from KCu_4S_3 to KCu_3S_2 . Since there are discrepancies in the literature concerning the syntheses of these materials, we report our synthesis with some detail.

Rudorff¹ first reported that by reacting 6 g potassium carbonate, 6 g sulfur and 1 g copper powder (K_2CO_3 :S:Cu in 2.8:1:12 molar ratios), KCu_4S_3 or $K_3Cu_8S_6$ can be obtained. By slowly heating to a specified temperature and soaking at that temperature for a specified time, either KCu_4S_3 (800 °C, 1 h) or $K_3Cu_8S_6$ (1000 °C, 3 h) can be the resultant product. The single-crystal x-ray diffraction study by Brown⁴ demonstrated that KCu_4S_3 can indeed be synthesized in this manner. However, any systematic attempts to change the procedure in order to improve crystal size or quality, were generally unsuccessful. Burschka⁶ was attempting to synthesize $K_3Cu_8S_6$ by Rudorff's method (1000°C, 3 h) when he discovered the as yet unknown phase, KCu₃S₂. His final results indicated that KCu₃S₂ was best synthesized in the temperature range 780-850°C wit a one-hour soak period. His report simply concluded that at lower temperatures, both KCu₄S₃ and K₃Cu₈S₆ could be identified in powder x-ray diffraction patterns, but did not elaborate. In his later study, Burschka⁷ reported that $K_3Cu_8S_6$ was indeed obtainable from a lower, but somewhat narrow temperature range. At 790 °C he found that the formation of KCu₄S₃ and/or K₃Cu₈S₆ could be controlled by the length of the soak period. Specifically, two hours led to a product which yielded x-ray quality crystals of K₃Cu₈S₆.

In our own initial attempts to synthesize $K_3Cu_8S_6$, we actually synthesized several unwanted batches of either KCu_4S_3 or KCu_3S_2 . $K_3Cu_8S_6$ would sometimes appear only as the minor second phase in a few of the multiphase batches. K₃Cu₈S₆ crystals are needlelike, and as such, are easy to separate from the layerlike crystals of KCu₄S₃. On the other hand, KCu_3S_2 crystals are also needlelike and for all practical purposes, indistinguishable from K₃Cu₈S₆. So, if a few x-ray-quality-sized crystals is all that is desired, the mixed-phase system of KCu₄S₃- $K_3Cu_8S_6$ is the system of choice since the two materials can be easily distinguished from one another. However, in order to obtain bulk single-phase K₃Cu₈S₆ product, and in order to clarify the discrepancies in the literature, we have attempted to define the syntheses of these materials more precisely.

We initially held to Rudorff's prescribed amounts of starting material (6 g K_2CO_3 , 6 g S, 1 g Cu) since we felt the large excess of potassium and sulfur was necessary to provide a growth medium for the crystals (a hypothesis later verified by experiments discussed below). The starting materials were ground together and placed into an alumina crucible which was deep enough to contain the initial bubbling (foaming) which occurs upon heating. The crucible was covered with a tight fitting alumina cap, and then placed inside a long and deep carbon crucible. This carbon crucible was then placed inside a vertical quartz tube which was contained inside a vertical tube furnace. Without the graphite crucible, K₂CO₃ vapor attacked the quartz tube irreversibly. Provisions at the top of the quartz tube allowed the system to be sealed off with an inert gas flow (argon) and the insertion of a thermocouple down to the reaction zone. The quartz vessel was long enough such that some of it was exposed to roomtemperature air in order to keep it cool enough so that excess sulfur would condense on the quartz walls and not inside the gas-glow tubing (where blockage could occur).

After sufficient flushing of the reaction vessel with the argon, a small flow rate of argon (1 bubble/sec in oil bubbler) was maintained throughout the reaction process. Figure 1 is a plot of our synthesis results in terms of set-point temperature versus soak period. The heating rate from room temperature to the set point was 125° C/h. To cool the reaction, the furnace was simply shut off at the end of



FIG. 1. By plotting the reaction soak period versus soak temperature, the observed trend becomes self-evident. The cleanest $K_3Cu_8S_6$ can be isolated around 875 °C and 1–2 h. The area between the two dashed lines indicates the conditions under which at least some $K_3Cu_8S_6$ can be observed along with either KCu_4S_3 or KCu_3S_2 .

the soak period and allowed to cool down at a rate of approximately 125°C/h. Figure 1 demonstrates the relationship we began to notice after several runs. In general, KCu_4S_3 and KCu_3S_2 are the predominant phases in the reaction system. The lower-temperature phase is KCu₄S₃, and the higher temperature phase is KCu₃S₂. The boundary between these two phases varies from approximately 900°C to 800°C, depending on the length of the soak period. Clean material of either KCu_4S_3 or KCu_3S_2 can be made by using reaction conditions well removed from the boundary lines as indicated in Fig. 1. In between the boundary lines is where $K_3Su_3S_6$ can be found as a product. The data in Fig. 1 indicate that a shorter soak period and higher soak temperature favor the formation of $K_3Cu_8S_6$. For soak periods of 5 h or longer, $K_3Cu_6S_6$ is hardly detectable in x-ray powder patterns since the boundary between KCu₄S₃ and KCu₃S₂ apparently becomes more crisply defined. The optimum conditions for synthesizing K₃Cu₈C₆ seem to be a soak temperature of 875 °C for a 1-2-h period. When soaked for less than one hour, the product is neither crystalline nor clean in terms of its x-ray powder diffraction pattern. Finally, the last parameter which we found to affect the reaction product was the particle size of the K_2CO_3 . The data in Fig. 1 are for well-ground materials. When coarser K₂CO₃ was used, the effective boundary line shifted to a higher temperature and/or a longer time. We interpret this as a result of the kinetics of K₂CO₃ decomposition and its reaction with sulfur. Smaller K₂CO₃ particles simply allow for faster kinetics due to their increased surface area with

respect to larger particles. Since the formation of $K_3Cu_8S_6$ is sensitive towards the reaction time and temperature, it is actually not surprising that the K_2CO_3 particle size would also have a pronounced effect on $K_3Cu_8S_6$ formation. By all evidence, $K_3Cu_8S_6$ seems to be a kinetic phase (i.e., nonequilibrium) and as such, must be "trapped" under the best available conditions. Our cleanest product was greater than ~95% pure $K_3Cu_8S_6$. The small amount of KCu_4S_3 was easily recognizable (platelets) and manually separated from the $K_3Cu_8S_6$ crystals.

The actual workup of the cooled cake is straightforward. Since the cooled cake is usually firmly stuck in the alumina crucible, it is filled with a deoxygenated 50:50 mixture of ethanol and distilled water to leach out the soluble polysulfides. The yellow solution is decanted off after some time is allowed for the leaching to occur (ultrasonic agitation helps), and then the process is repeated. When the solution becomes colorless and odorless, the leaching process is complete and shiny blue-black crystals should be all that remain. After suction filtering the crystals under an argon flow, they are washed with absolute ethanol and anhydrous ethyl ether. The crystals can then be thoroughly dried under vacuum. K₃Cu₈S₆ crystals are needlelike crystals that are similar in overall appearance to the KCu_3S_2 crystals. KCu_4S_3 crystals form easily recognizable platelets. If K₃Cu₈S₆ crystals are left exposed to the atmosphere, they will lose their metallic lustre over the course of a few days due to oxidation reactions with moist air. Product batches were characterized by powder x-ray diffraction. Powder patterns for the pure materials are displayed in Fig. 2 and demonstrate that mixtures can be easily identified since many diffraction peaks do not overlap between the three phases. The relative purity of product batches was estimated from the diffraction pattern intensities as well as by visible examination in the case of KCu₄S₃-K₃Cu₈S₆ mixtures.

III. RESULTS

A. Magnetism

Magnetic susceptibility data for K₃Cu₈S₆ were obtained using a cryogenically equipped Faraday balance at an externally applied magnetic field of 10.6 kG and a gradient of 0.939 kG/cm.⁹ The data are displayed in Fig. 3 using two different formats. The upper curve represents the experimentally observed gram susceptibility. The data were collected with the temperature decreasing as well as with the temperature increasing at rates of 0.5-1.0K/min. The rising susceptibility at low temperatures in the upper curve is due to a Curie contribution from paramagnetic impurities. Hence, the data below 15 K were fit to the form $\chi_0 + C/(T + \Theta)$, where χ_0 is assumed to be temperature independent and $C/(T+\Theta)$ accounts for the paramagnetic impurity $(C=3.573, \Theta=0)$ and is subtracted out of the entire upper curve in Fig. 3 to yield the lower curve. The lower curve is assumed to be the intrinsic susceptibility and is the sum of the diamagnetic core contributions and the Pauli-Landau and Van-Vleck paramagnetic contributions. The magnetic susceptibility is only weakly temperature dependent above 180 K, but shows a stronger temperature dependence indicative of phase transitions below 180 K. There is a reversible transition (probably second order) at approximately 150 K which is more clearly displayed in the derivative $d\chi_{o}/dT$ as shown in Fig. 4. The curve for $d\chi_g/dT$ is obtained by fitting the observed χ_g data to a quadratic polynomial for every eight consecutive data points. The linear coefficient is then extracted and plotted versus temperature to yield the $d\chi_g/dT$ versus T curve. In the region of 50 K there is a first-order transition with considerable hysteresis. A pretransition "dip" in the susceptibility appears at about 60-65 K in the cooling curves, but not in the heating curve.



FIG. 2. Powder x-ray diffraction patterns for KCu₄S₃, K₃Cu₈S₆, and KCu₃S₂. KCu₄S₃: tetragonal, a = 3.899 Å, c = 9.262 Å. K₃Cu₈S₆: monoclinic, a = 17.332 Å, b = 3.83 Å, c = 9.889 Å, $\beta = 104.12^{\circ}$. KCu₃S₂: monoclinic, a = 14.773 Å, b = 3.946 Å, c = 8.182 Å, $\beta = 113.5^{\circ}$.

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FIG. 3. Magnetic susceptibility data for $K_3Cu_8S_6$. Upper curve is the experimentally observed data during cooling and heating. The lower curve is the cooling data minus an impurity Curie term.

B. Conductivity

Temperature-dependent electrical-resistivity measurements were made using the single crystal, four-probe method. A typical crystal of dimensions 0.15 mm×0.15 $mm \times 2.0$ mm was mounted with ultrasonic indium solder to four gold leads along the needle axis (b axis). Initially, conducting silver epoxy was used for contacts, but these were found to react (perhaps $Ag^+ \leftrightarrow Cu^+$ ion exchange with the crystal) and the contact resistance became quite large after several hours. The room-temperature resistance of the crystal was measured as 0.24 Ω . The distance between the two voltage contacts measured approximately 1 mm, and hence, the room-temperature resistivity can be calculated to be $5 \times 10^{-4} \ \Omega \text{ cm}$. An uncertainty of $\pm 30\%$ is estimated from the size of the contacts and the irregular crystal shape. The crystal exhibited ohmic behavior at room temperature, as well as stability of the contact resistance over the course of days.

Temperature dependence of the observed resistance of



FIG. 4. Magnetic susceptibility derivative $d\chi_g/dT$ obtained by numerically differentiating the corrected susceptibility. The peak at 152 ± 1 K indicates a second-order, reversible transition.



FIG. 5. Temperature dependence of the experimentally observed resistance for a single crystal of $K_3Cu_8S_6$. The room-temperature resistance of 0.24 Ω corresponds to a resistivity of $5 \times 10^{-4} \Omega \text{ cm} (\pm 30\%)$.

the crystal is plotted in Fig. 5 for the range 5-350 K. The resistance decreases with decreasing temperature, indicative of metallic behavior down to about 160 K. There is a reversible phase transition at about 150 K which corresponds well with the phase transition observed at 152 ± 1 K in the magnetic susceptibility. Upon further cooling, the resistance rises until about 63 K, where there is a small dip in the resistance, just as there is in the magnetic susceptibility. Further cooling shows a dramatic decrease in resistance and leads to a state which is again metallic in the region of 5-50 K. The heating curve demonstrates that a considerable hysteresis exists and that it extends up to at least 100 K. As in the case of the magnetic susceptibility, the heating curve does not display the anomaly near 63 K. Figure 6 shows dR/dT versus temperature and again show that the second-order phase transition occurs at about 152 K. As in the case of the magnetic susceptibility, the derivative was obtained by fitting the experimental data to a quadratic polynomial for every eight consecutive points, and extracting the linear coefficient as the slope.

C. Specific heat

The specific heat of $K_3Cu_3S_6$ was measured¹⁰ in the temperature range of 100 K to 300 K. The specific heat



FIG. 6. The derivative dR/dT plotted as a function of temperature demonstrates the existence of the second-order phase transition at 153 K as well as the broad hysteresis due to the first-order transition.



FIG. 7. Specific-heat data for K₃Cu₈S₆ display a reversible anomaly near 150 K.

shows no unusual behavior down to 160 K, and is almost constant. As shown in Fig. 7, there is a small peak in the region of 150 K, and both heating and cooling runs gave the same curve. This corresponds to the reversible phase transition seen in both the magnetic susceptibility and the electrical resistivity. The slope of the specific heat is more positive below the transition region than it is above the transition region.

IV. DISCUSSION

A relatively large number of copper-sulfide phases are known and most contain discrete oxidation (valence) states.⁴ The major exception is the $Cu_{2-x}S$ $(0 \le x \le 0.2)$ binary system where a variety of nonstoichiometric, "mixed-valence" phases can be found. An additional exception lies in the K-Cu-S system, of which K₃Cu₈S₆, KCu_4S_3 , and KCu_3S_2 are members, but only $K_3Cu_8S_6$ and KCu₄S₃ provide mixed-valence examples.

Although it is tempting to describe copper-sulfur mixed-valence compounds as Cu^ICu^{II} systems, most of the available evidence suggests that the mixed-valency resides primarily on the sulfur and not on the copper. 1^{1-13} X-ray photoelectron spectroscopy suggests that all known copper sulfides (including $Cu_{2-x}S$, KCu_4S_3 , and $Na_3Cu_4S_4$) contain only Cu(I). There is no direct evidence to date that shows that Cu(II) or intermediate oxidation states exist in these copper-sulfide phases. With these results in mind, the mixed-valency in KCu₄S₃ might be formulated as $K^+C_4^+(S^{2-})_2S^-$. Similarly, another example is provided by $Na_3^+Cu_4^+(S^{2-})_3S^-$ in $Na_3Cu_4S_4$. As such, we can formulate $K_3Cu_8S_6$ as a Robin-and-Day¹⁴ class IIIB mixed-valence material with the formula $K_3^+Cu_8^+(S^{2-})_5S^-$. These ioniclike notations are useful primarily for descriptive purposes and are consistent with results from photoelectron spectroscopy of copper sulfides. However, it is clear that covalency is very important in these phases, and it is likely that the wave functions at the Fermi surface of these metallic compounds have considerable copper as well as sulfur character.

As a class IIIB mixed valence material, K₃Cu₈S₆ could be expected to show metallic behavior. The electrical resistivity results confirm this with a drop in resistivity of approximately two orders of magnitude from 300 to 5 K. The absolute value of the resistivity [ρ (300 K) \cong 5 \times 10⁻⁴ Ω cm] is similar in value to other metallic phases with layered structures.¹⁵

From a structural point of view, K₃Cu₈S₆ is also an interesting material. The crystal structures of KCu₄S₃, K₃Cu₈S₆, and KCu₃S₂ are shown in Fig. 8. The lowtemperature phase KCu₄S₃ is a close-packed doublelayered structure (S-Cu-S-Cu-S) in which all copper ions are tetrahedrally coordinated.⁴ The high-temperature phase, KCu₃S₂, is also a layered structure but has a pleated character because the copper ions are in both tetrahedral and trigonal coordination sites.⁶ A remarkable feature of KCu_3S_2 is that one-dimensional chains of $[Cu_4S_4]^{n-1}$ of infinite length, which we will denote by ${}_{\infty}^{1}$ [Cu₄S₄]^{*n*-, are bridged by edge-sharing tetrahedra to}



FIG. 8. Representations of the structures of KCu₄S₃, $K_3Cu_8S_6$, and KCu_3S_2 . In $K_3Cu_8S_6$, note how Cu(1), Cu(3), S(1), and S(3) form a small segment of half of the double layer found in KCu_4S_3 , while Cu(2), Cu(4), S(2), and S(3) form the ${}_{m}^{1}$ [Cu₄S₄]^{*n*-} component of the layered structure. In all cases, the potassium ions separate the layered structures.

yield the pleated layers, which are separated by potassium ions. The structure of $K_3Cu_8S_6$ is intermediate between that of KCu_4S_3 and KCu_3S_2 .⁷ It is not surprising then that the $K_3Cu_8S_6$ synthesis conditions are "intermediate" between the syntheses of KCu_4S_3 and KCu_3S_2 . Additionally, the stoichiometric sequence

$$K_{2}Cu_{8}S_{6} \xrightarrow{K} K_{3}Cu_{8}S_{6} \xrightarrow{Cu} K_{3}Cu_{9}S_{6}$$
(2)

also suggests that $K_3Cu_8S_6$ might be an intermediate structure.

 $K_3Cu_8S_6$ is most like KCu_3S_2 in that the $\frac{1}{\infty}[Cu_4S_4]^{n-1}$ chain is an integral part of the layer structure. Figure 9 schematically demonstrates how this vital part of $K_3Cu_8S_6$ is based upon trigonal coordination of the copper ions. These resultant $\frac{1}{\infty} [Cu_4 S_4]^n$ chains are bonded into layers using edge-sharing tetrahedra that resemble a small segment of half of the double layer found in the KCu₄S₃ structure. The crystal structure report by Burschka shows that the Cu3 ions, which are the heart of this bridging network between $\frac{1}{\infty} [Cu_4 S_4]^n$ chains, have either a large amount of thermal motion or a slight disorder.⁷ (This is indicated in Fig. 8 by the elliptical shapes assigned to the Cu3 ions.) It is interesting to note at this point that the idea of a ${}^{1}_{\infty}$ [M₄S₄]^{*n*-} chain is also evident in other structures. Figure 10 demonstrates that $Na_3Cu_4S_4$ and $K_2Ag_4S_3$ also possess this columnar chain as the fundamental unit of their solid-state structure. It is clearly the manner in which this columnar chain packs into the lattice that is responsible for the overall differences in structure. In the case of $K_3Cu_8S_6$ (as well as the others) the packing of these $\frac{1}{\infty} [Cu_4 S_4]^{n-1}$ chains into layers results in layers which have an anisotropic character, unlike the more conventional layered materials such as NbSe₂, TaS₂, etc.

The electrical resistivity and magnetic susceptibility for $K_3Cu_8S_6$ clearly show the presence of phase transitions in the region of 55 and 150 K. The most likely explanation for the observed behavior in $K_3Cu_8S_6$ is the presence of a charge-density wave (CDW). Charge-density waves are most common in lower-dimensional materials (metals) such as NbSe₃ (one-dimensional) and TaSe₂ (two-



FIG. 9. Schematic representation of how the vital ${}^{1}_{\infty}[Cu_4S_4]^{n-}$ structure is obtained from trigonally coordinated cooper ions. The sheet of trigonally coordinated copper on the left is wrapped around (so that dashed lines meet) to yield the columnar chain structure on the right.



FIG. 10. Structures for Na₃Cu₄S₃ and K₂Ag₄S₃. The views down the *b* axes $\binom{1}{\infty} [Cu_4S_4]^{n-}$ chain axis) demonstrate the similarity to the K-Cu-S systems.

dimensional) but are occasionally seen in three-dimensional materials such as CuV_2S_4 .¹⁶ The simplest models suggest that CDW formation is favored in lowdimensional metals because anisotropic Fermi surfaces with regions of low curvature are expected to occur, while in three-dimensional materials such occurrences are "accidental."¹⁷ K₃Cu₈S₆ is clearly a lower-dimensional metal. However, the layers of K₃Cu₈S₆ have an anisotropic two-dimensional character because of the manner in which the layers are composed of chains. The crystal dimensions were too small to obtain a measure of the electrical in-layer anisotropy, but the retention of metallic behavior below the transitions suggests that the anisotropy is not large enough to make the system quasi-onedimensional. Such large anisotropies do exist in some structurally two-dimensional metals so that the CDW properties are effectively one dimensional (for example, in $K_{0.3}MoO_3$).¹⁸ Since $K_3Cu_8S_6$ meets the structural criteria and can be considered a low-dimensional metal, CDW formation is a likely explanation for the observed magnetic susceptibility and electrical resistivity based on the similar behavior of precedent systems.¹⁷ In particular, the observed behavior of K₃Cu₈S₆ is very similar to CuV₂S₄.¹⁶ The major difference is the enhanced value of the magnetic susceptibility in CuV_2S_4 due to electron-electron interactions, as well as the actual temperatures of the transitions. The magnitude of the relative behavior in terms of changes in susceptibility at the phase transitions is, however, very similar between $K_3Cu_8S_6$ and CuV_2S_4 . However, observation of an incommensurate lattice modulation in a metal is what is really needed in order to show CDW formation. Our preliminary low-temperature singlecrystal x-ray diffraction results do indeed indicate that the phase transition at 153 K produces an incommensurate state with a wave vector $\mathbf{q} = (1-\delta)\mathbf{b}^*/2$ where $\delta(150$ $K) \simeq 0.1$ (note that \mathbf{b}^* is parallel to b, which lies along the needle axis). The distortion becomes commensurate at the first-order transition near 55 K. This structural data coupled with the physical properties strongly suggest CDW formation in $K_3Cu_8S_6$. Further x-ray work is in progress and will be reported later.

V. CONCLUSION

We have refined and explained the previously confusing synthesis of the interesting structure $K_3Cu_8S_6$. Based on

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structural similarities to KCu_4S_3 and KCu_3S_2 , we conclude that $K_3Cu_8S_6$ is a kinetic phase which must be carefully "trapped." Investigation of the electrical resistivity and magnetic susceptibility has led us to suggest that CDW formation is responsible for the phase transitions in $K_3Cu_8S_6$. Based on the mixed valency (e.g., metallic properties) and the low-dimensional structure of $K_3Cu_8S_6$, CDW formation is indeed likely. X-ray results confirm the presence of an incommensurate lattice below 150 K. Future results will be reported on in order to structurally describe the CDW phenomena in $K_3Cu_8S_6$.

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